

Description

The HTU7G06S001P is an unmatched discrete LDMOS Power Amplifier with 1W saturated output power covering frequency range for VHF/UHF applications.

Features

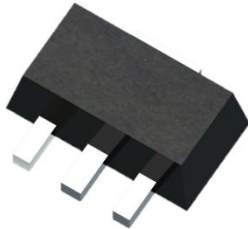
- Operating Frequency Range: VHF/UHF
- Operating Drain Voltage: +4V
- Saturation Output Power: 1W
- Enhanced robustness design without device degradation
- Internally integrated enhanced ESD design

Freq (MHz)	Vdd (V)	Pout (W)	Eff (%)
430	4.0	1.3	65


Test conditions unless otherwise noted: 25 °C,
 $V_{DD} = +4Vdc$, $I_{DQ} = 100mA$, CW Signal

Applications

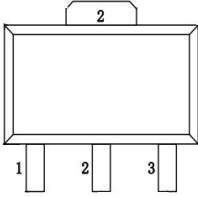
- VHF Band handheld Walkie-talkie
- UHF Band handheld Walkie-talkie
- 1.8-1000MHz other application Drivers or Final stage Amplifiers




SOT-89-3L
HTU7G06S001P

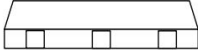


OUTLINE DRAWING





Terminal No.
 1 : Gate
 2 : Source
 3 : Drain
 UNIT: mm



Note: Exposed backside of the package is the source terminal for the transistor

Pin Connections

Ordering Information

Part Number	Description
HTU7G06S001P	Reel Package
HTU7G06S001PEVB	400 - 470 MHz EVB

Absolute Maximum Ratings

Parameter	Range/Value	Unit
Drain voltage (V_{DSS})	-0.5 to +17	V
Gate voltage (V_{GS})	-5 to +10	V
Operation voltage (V_{DD})	+8.5	V
Storage Temperature (T_{STG})	-55 to +150	°C
Junction Temperature (T_J)	-40 to +150	°C
Thermal Resistance Junction to Case (R_{TH})	25	°C/W

Electrical Specification

DC Characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Breakdown Voltage $V_{(BR)DSS}$	$V_{GS}=0V, I_{DS}=16\mu A$	17	-	-	V
Gate-Source Threshold Voltage $V_{GS(th)}$	$V_{DS}=V_{GS}, I_{DS}=16\mu A$	0.5	1.0	1.5	V
Drain Leakage Current I_{DSS}	$V_{GS}=0V, V_{DS}=17V$	-	-	1	μA
Gate Leakage Current I_{GSS}	$V_{GS}=10V, V_{DS}=0V$	-	-	1	μA

Load Mismatch Test

Condition	Test Result
VSWR=20:1, at all Phase Angles, $V_{DD} = +8.4V_{dc}$, $I_{DQ} = 100mA$, CW signal 35 dBm @435MHz test on WATECH Application Board	No Device Degradation

RF Characteristics (CW)

Freq (MHz)	Vdd (V)@Idq (mA)	Pin (W)	Pout (W)	Eff (%)
430	4.0@100	0.1	1.3	65

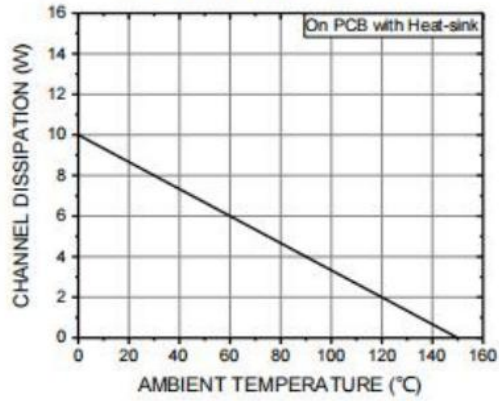
Test conditions unless otherwise noted: 25 °C test on WATECH Application Board

Freq (MHz)	Vdd (V)@Idq (mA)	Pin (W)	Pout (W)	Eff (%)
430	7.2@100	0.13	3.2	65

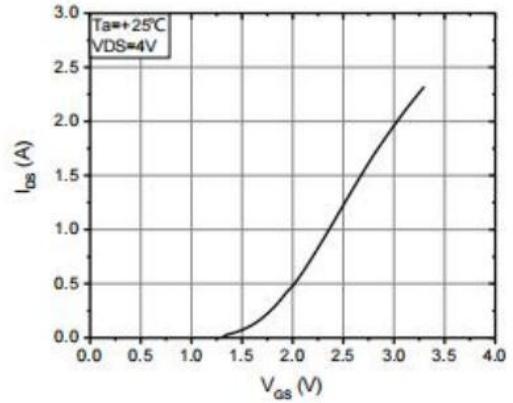
Test conditions unless otherwise noted: 25 °C test on WATECH Application Board

DC Performance

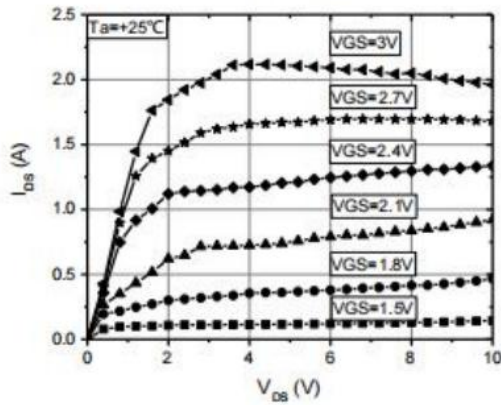
**CHANNEL DISSIPATION VS.
AMBIENT TEMPERATURE**



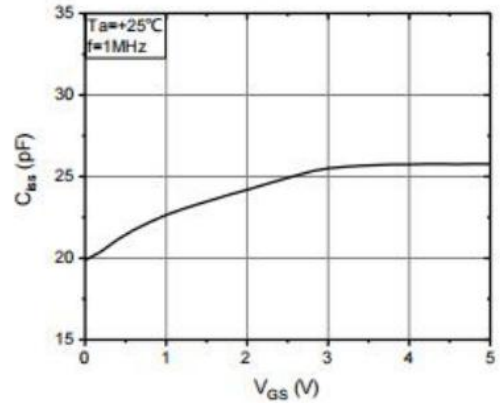
I_{DS} VS. V_{GS}



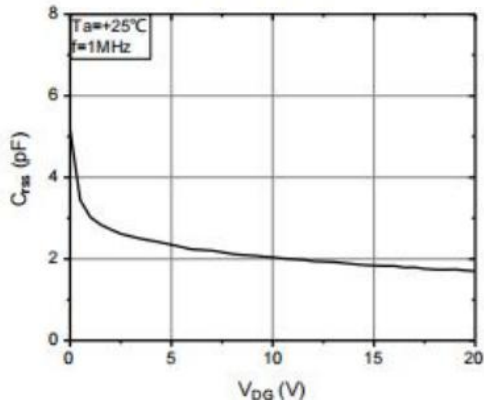
I_{DS} VS. V_{DS}



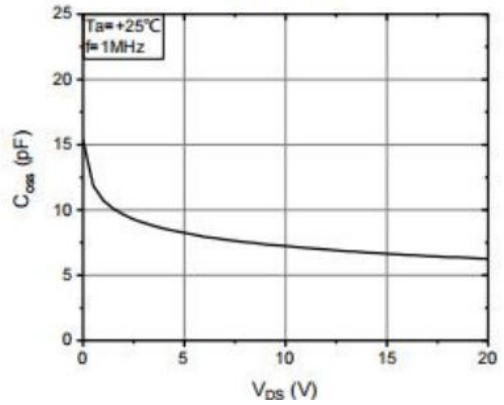
C_{iss} VS. V_{GS}



C_{rss} VS. V_{DS}

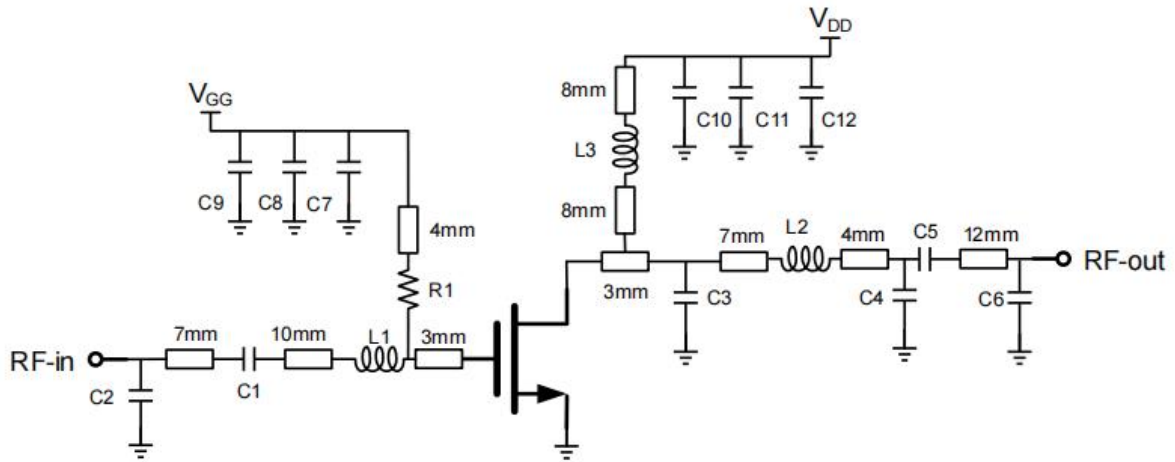


C_{oss} VS. V_{DS}



Test conditions unless otherwise noted: 25 °C

HTU7G06S001P 400 - 470 MHz Reference Design, 4.0V@100mA

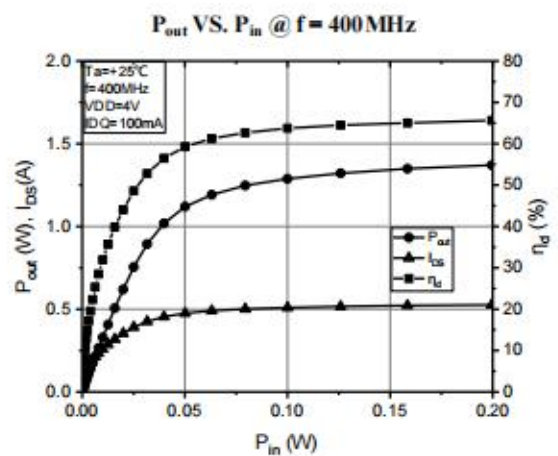
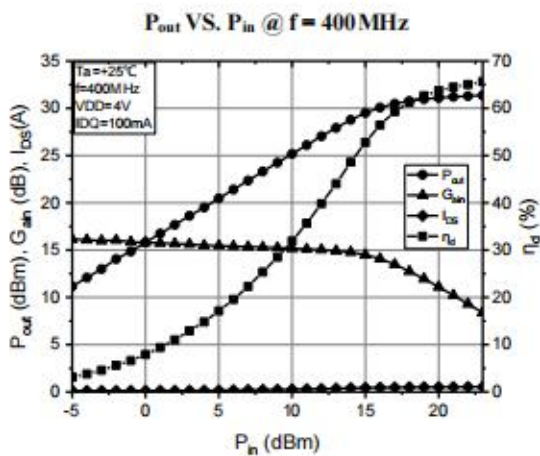
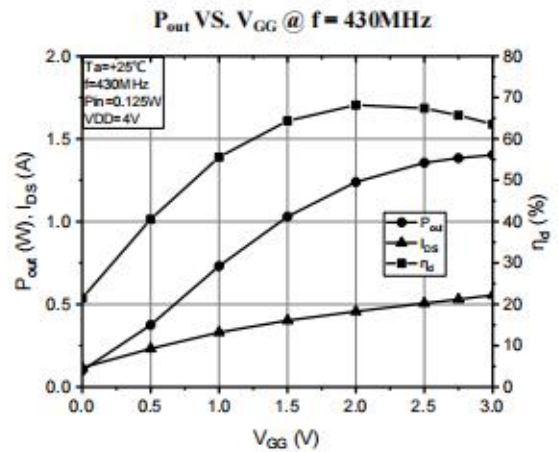
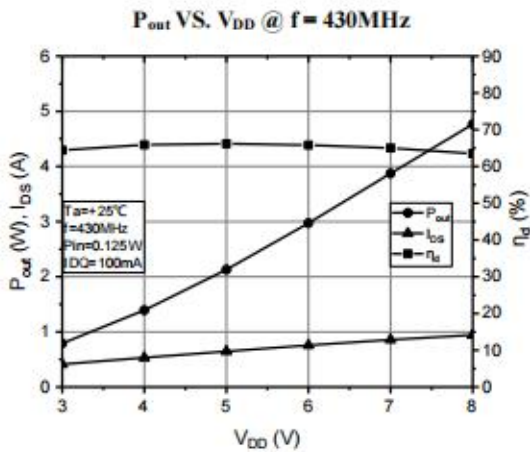
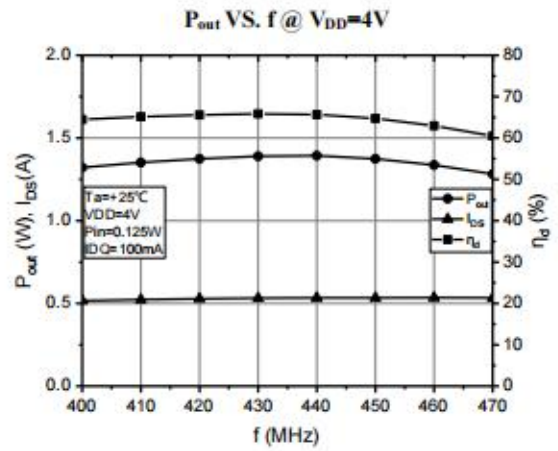
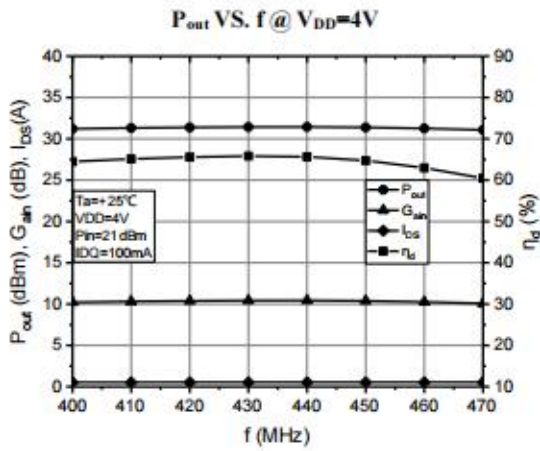


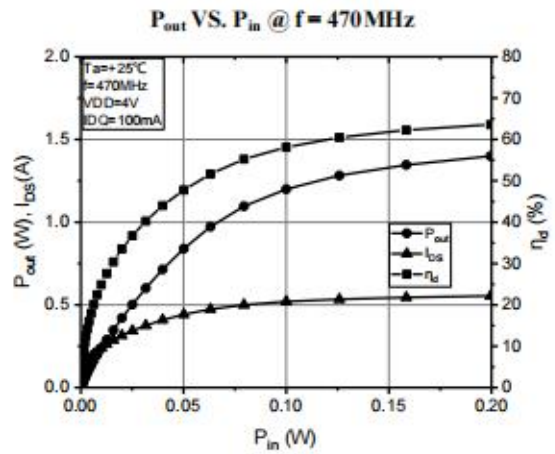
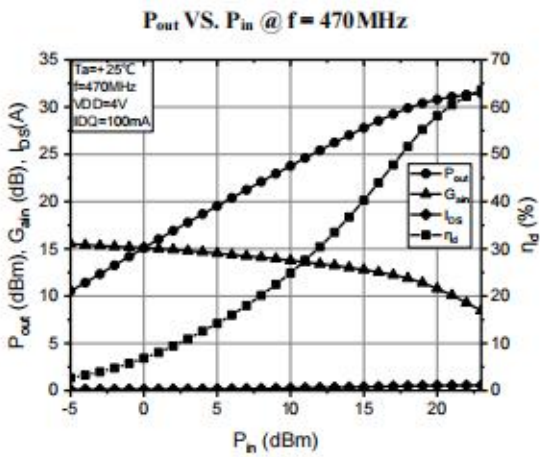
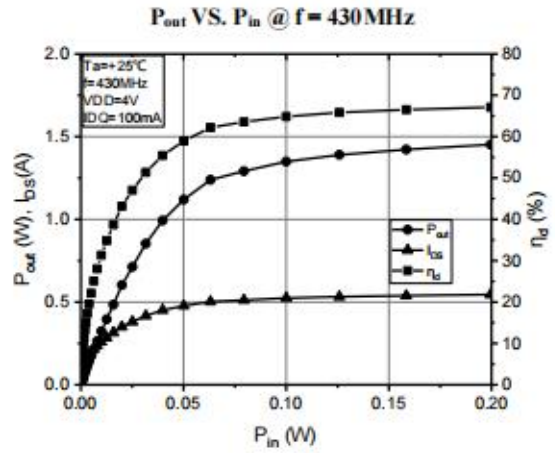
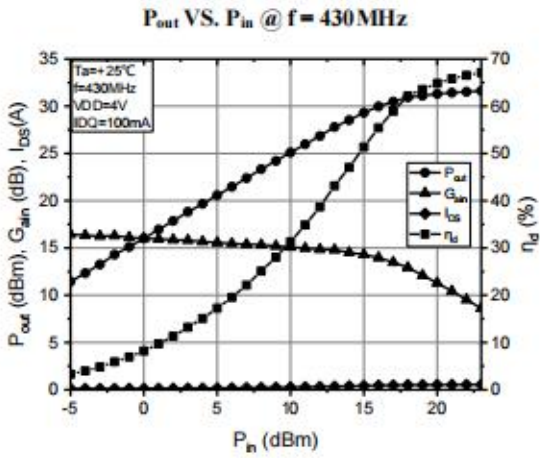
EVB Layout

BoM - HTU7G06S001P 400 - 470 MHz Reference Design, 4.0V@100mA

Reference	Value	Description	Manufacturer	P/N
Q1	-	1W, 1.8 - 1000 MHz LDMOS PA	Watech	HTU7G06S001P
C1, C5, C7, C10	220pF	MLCC	Murata	GRM1885C1H221JA01
C2	15pF	MLCC	Murata	GRM1885C1H150JA01
C3	27pF	MLCC	Murata	GRM1885C1H270JA01
C4	3pF	MLCC	Murata	GRM1885C1H3R0JA01
C6	6pF	MLCC	Murata	GRM1885C1H6R0JA01
C8, C11	1nF	MLCC	Murata	GRM1885C1H102JA01
C9	4.7uF	MLCC	Murata	GRM32ER61H474KA12L
C12	10uF	MLCC	Murata	GRM32ER61H105KA12L
L1	2.7nH/0603		-	-
L2	D: 0.3 mm, Inside: 1.50 mm, 2 Turns		-	Enameled wire
L3	D: 0.3 mm, Inside: 1.5 mm, 2 Turns		-	Enameled wire
R1	100 Ω	Thick Film Resistor	-	-
PCB	FR-4 (er = 4.3), 30 mil (0.762 mm), 35 μm (1oz)			

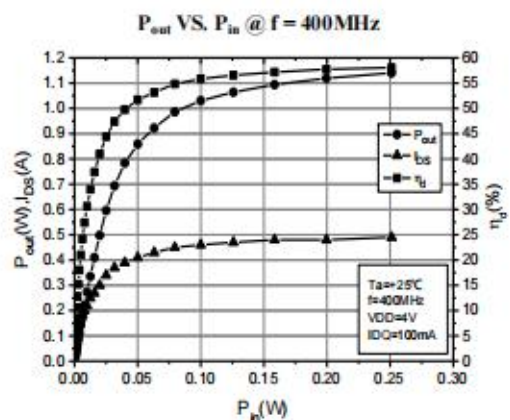
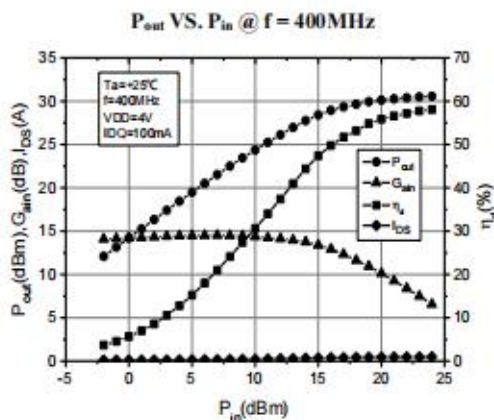
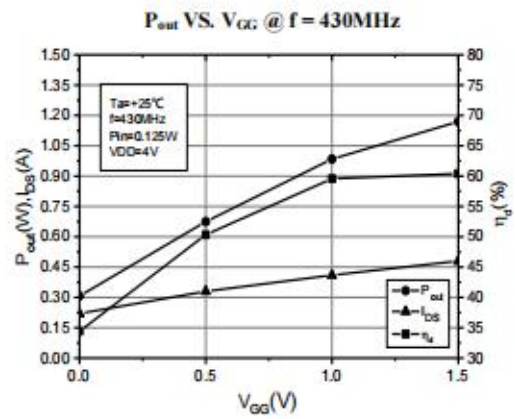
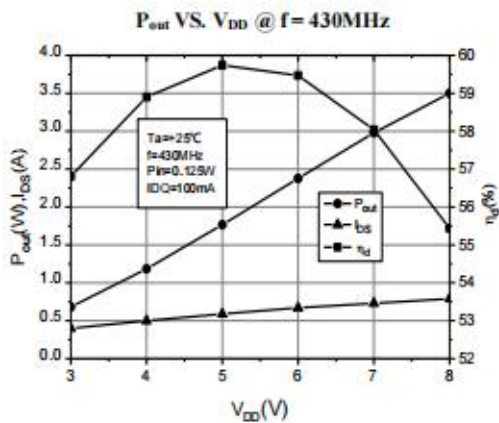
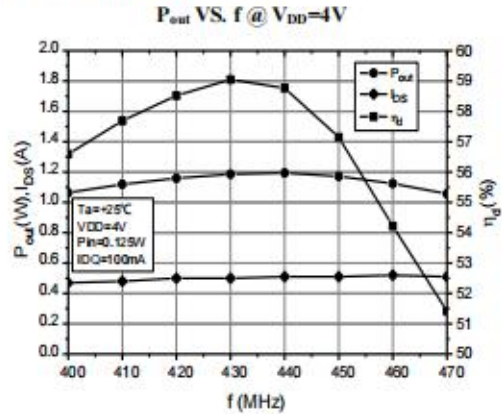
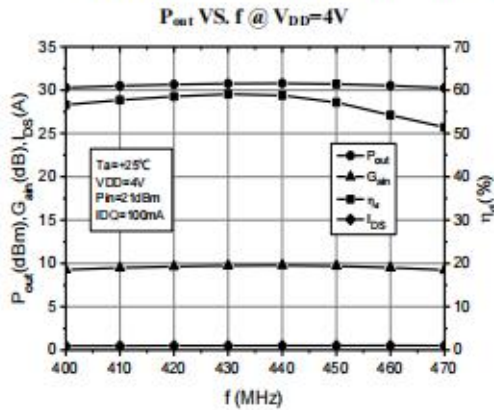
Performance Plots 400 - 470 MHz Reference Design, 4.0V@100mA

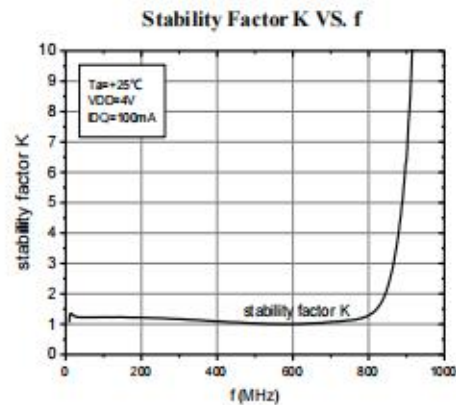
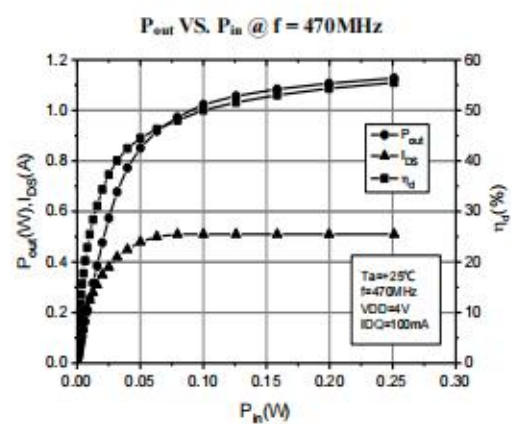
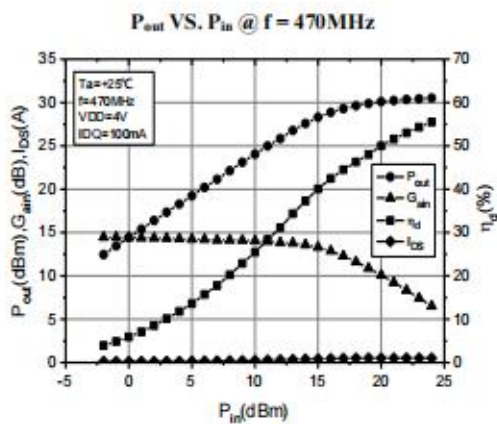
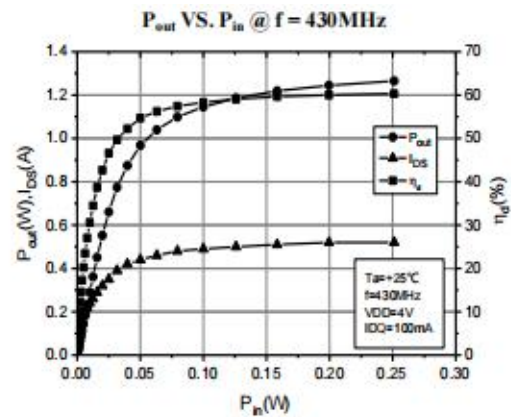
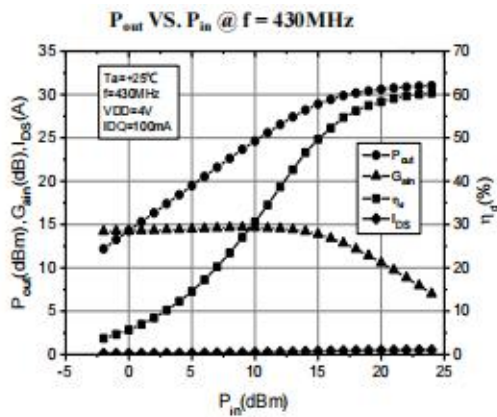




Test conditions unless otherwise noted: 25 °C, V_DD = +4Vdc, I_DQ=100mA, CW test on WATECH Application Board

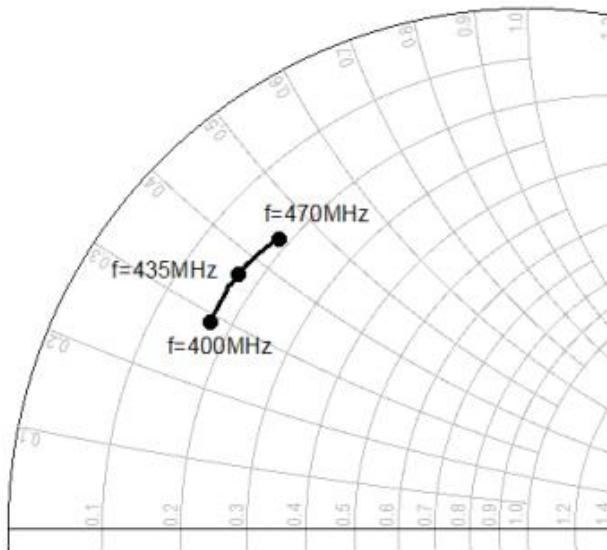
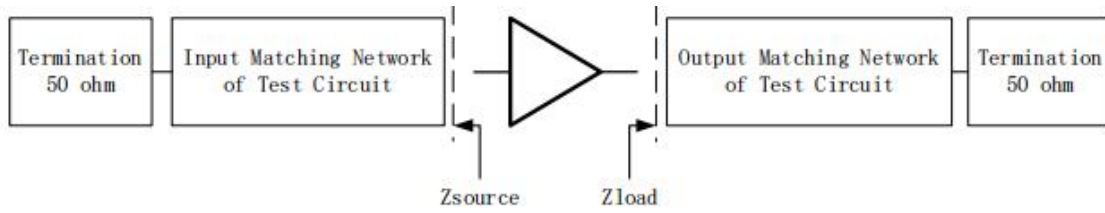
The Test Circuit is Absolutely Stable in the UHF-band with Feedback



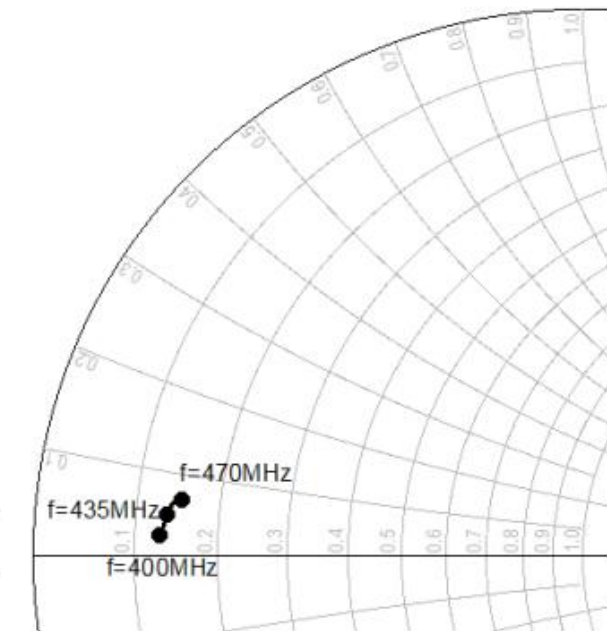


Test conditions unless otherwise noted: 25 °C, VDD = +4Vdc, IDQ=100mA, CW test on WATECH Application Board

Input/Output Impedance Characteristics @4V, 400-470MHz



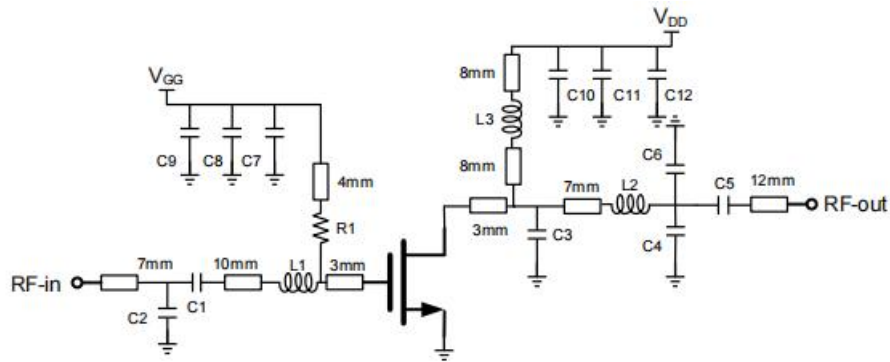
@Pin=0.125W, V _{DD} =4V, I _{DQ} =100mA	
f(MHz)	Z _{source} (ohm)
400	8.49 + j 14.46
435	8.45 + j 18.21
470	9.03 + j 21.93



@Pin=0.125W, V _{DD} =4V, I _{DQ} =100mA	
f(MHz)	Z _{load} (ohm)
400	6.57 + j 1.61
435	6.91 + j 2.82
470	7.20 + j 3.31

Test conditions unless otherwise noted: 25 °C, V_{DD} = +4Vdc, I_{DQ}=100mA, CW test on WATECH Application Board

HTU7G06S001P 400 - 470 MHz Reference Design, 7.2V@100mA

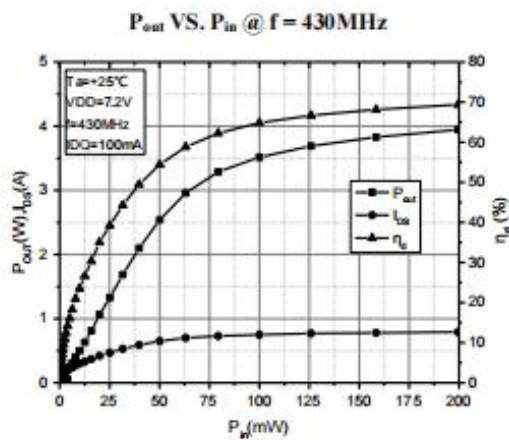
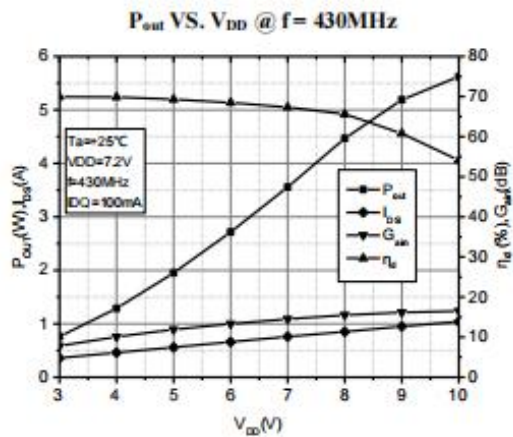
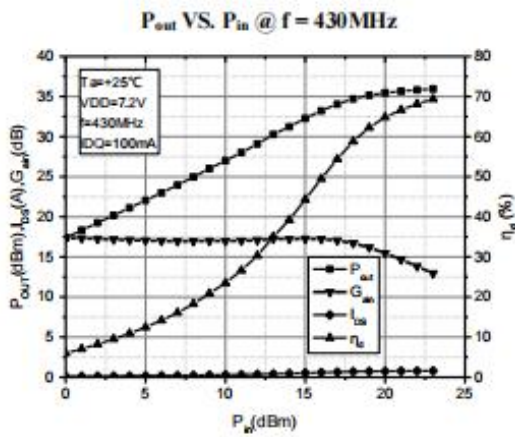
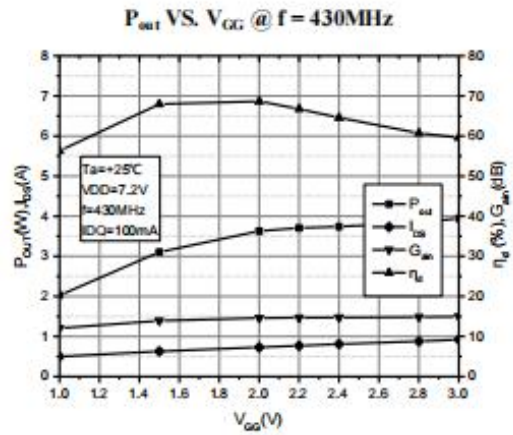
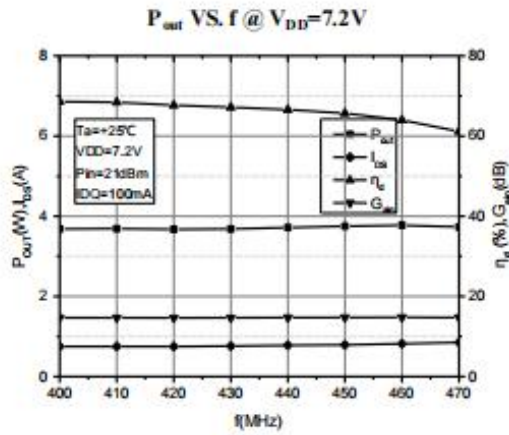


EVB Layout

BoM - HTU7G06S001P 400 - 470 MHz Reference Design, 7.2V@100mA

Reference	Value	Description	Manufacturer	P/N
Q1	-	1W, 1.8 - 1000 MHz LDMOS PA	Watech	HTU7G06S001P
C1, C5, C7, C10	220pF	MLCC	Murata	GRM1885C1H221JA01
C2	15pF	MLCC	Murata	GRM1885C1H150JA01
C3	27pF	MLCC	Murata	GRM1885C1H270JA01
C4	3pF	MLCC	Murata	GRM1885C1H3R0JA01
C6	6pF	MLCC	Murata	GRM1885C1H6R0JA01
C8, C11	1nF	MLCC	Murata	GRM1885C1H102JA01
C9	4.7uF	MLCC	Murata	GRM32ER61H474KA12L
C12	10uF	MLCC	Murata	GRM32ER61H105KA12L
L1	2.7nH/0603		-	-
L2	D: 0.3 mm, Inside: 1.50 mm, 2 Turns		-	Enameled wire
L3	D: 0.3 mm, Inside: 1.5 mm, 2 Turns		-	Enameled wire
R1	100 Ω	Thick Film Resistor	-	-
PCB	FR-4 (er = 4.3), 30 mil (0.762 mm), 35 μm (1oz)			

Performance Plots 400 - 470 MHz Reference Design, 7.2V@100mA



Test conditions unless otherwise noted: $25^\circ C$, $V_{DD} = +7.2V_{dc}$, $IDQ=100\text{ mA}$, CW test on WATECH Application Board

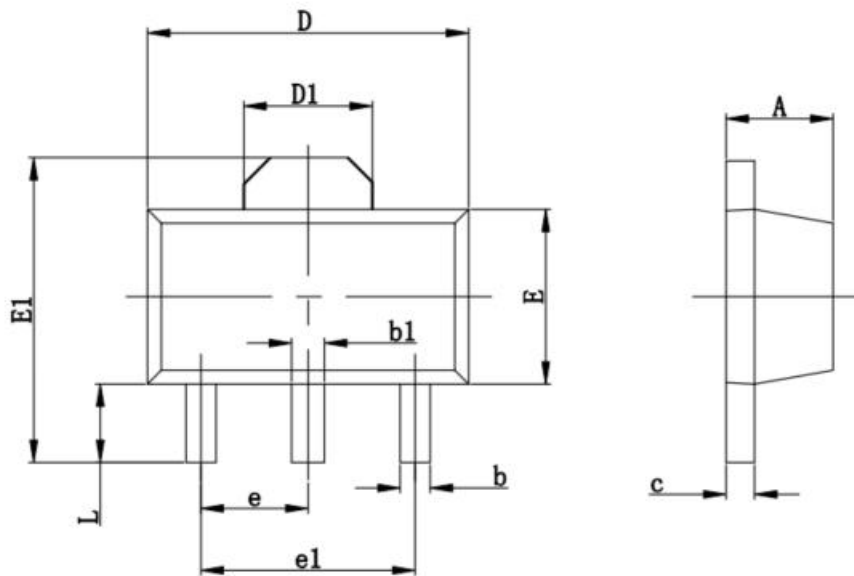
Package Marking and Dimensions



- Line1 (fixed): fixed code H0601A
- Line2 (unfixed): Date Code + SS(sub lot Number)

This Marking SPEC only stipulates the content of Marking. For marking requirements such as font and size, please refer to the latest version of “Watech Product Printing Specification”

Marking

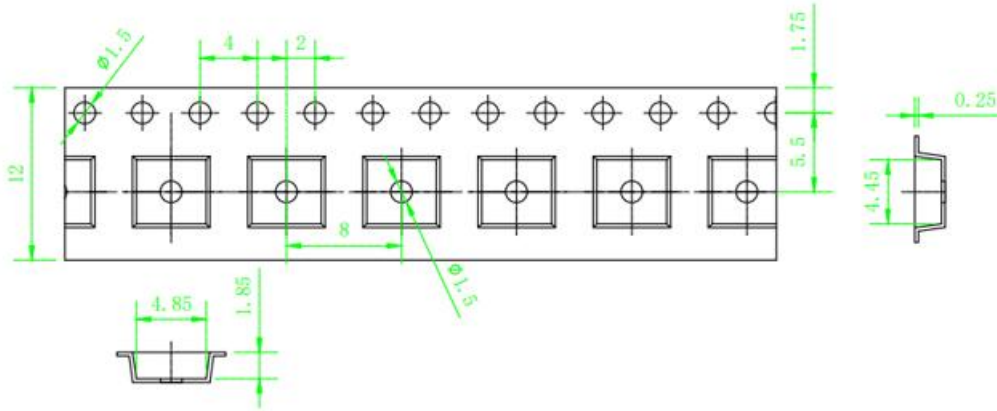


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.350	0.520	0.013	0.197
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF		0.061 REF	
E	2.350	2.550	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP		0.060TYP	
e1	3.000 TYP		0.118TYP	
L	0.900	1.100	0.035	0.047

Package Dimensions

Tape and Reel Information

Package Type	Reel Size(inch)	Qty/Reel(pcs)	Qty/Box(pcs)	Qty/Carton(pcs)
SOT89	7inch	1000	10000	40000



Tape & Reel Packaging Descriptions

Handling Precautions

Parameter	Rating	Standard	
ESD – Human Body Model (HBM)	Class 1B	JESD22-A114	
ESD – Human Body Model (MM)	Class A	EIA/JESD22-A115	
ESD – Charged Device Model (CDM)	Class III	JESD22-C101	

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

Datasheet Status

Document status	Product status	Definition
Objective Datasheet	Design simulation	Product objective specification
Preliminary Datasheet	Customer sample	Engineering samples and first test results
Product Datasheet	Mass production	Final product specification



Abbreviations

Acronym	Definition
LDMOS	Laterally-Diffused Metal-Oxide Semiconductor
CW	Continuous Waveform

Revision history

Document ID	Datasheet Status	Release Date	Revision Version
Rev 2.7	Product	March 2023	New format based on English version datasheet
Rev 2.8	Product	March 2024	Version released after re review



Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations and information about WATECH:

- Web: www.watechelectronics.com
- Email: MKT@huatai-elec.com

For technical questions and application information:

- Email: MKT@huatai-elec.com

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